

N-Channel JFET

PRODUCT SUMMARY			
$V_{GS(off)}$ (V)	$V_{(BR)GSS}$ Min (V)	g_{fs} Min (mS)	I_{DSS} Min (mA)
≤ -8	-25	2	2

FEATURES

- Excellent High-Frequency Gain:
Gps 11 dB @ 400 MHz
- Very Low Noise: 3 dB @ 400 MHz
- Very Low Distortion
- High ac/dc Switch Off-Isolation
- High Gain: $A_V = 60$ @ 100 μ A

BENEFITS

- Wideband High Gain
- Very High System Sensitivity
- High Quality of Amplification
- High-Speed Switching Capability
- High Low-Level Signal Amplification

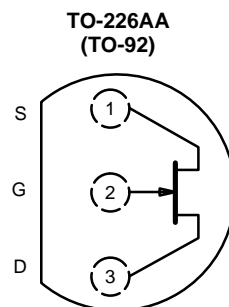
APPLICATIONS

- High-Frequency Amplifier/Mixer
- Oscillator
- Sample-and-Hold
- Very Low Capacitance Switches

DESCRIPTION

The 2N3819 is a low-cost, all-purpose JFET which offers good performance at mid-to-high frequencies. It features low noise and leakage and guarantees high gain at 100 MHz.

Its TO-226AA (TO-92) package is compatible with various tape-and-reel options for automated assembly (see Packaging Information). For similar products in TO-206AF (TO-72) and TO-236 (SOT-23) packages, see the 2N4416/2N4416A/SST4416 data sheet.



Top View

ABSOLUTE MAXIMUM RATINGS

Gate-Source/Gate-Drain Voltage	-25 V
Forward Gate Current	10 mA
Storage Temperature	-55 to 150°C
Operating Junction Temperature	-55 to 150°C

Lead Temperature ($1/16$ " from case for 10 sec.)	300°C
Power Dissipation ^a	350 mW

Notes
a. Derate 2.8 mW/°C above 25°C

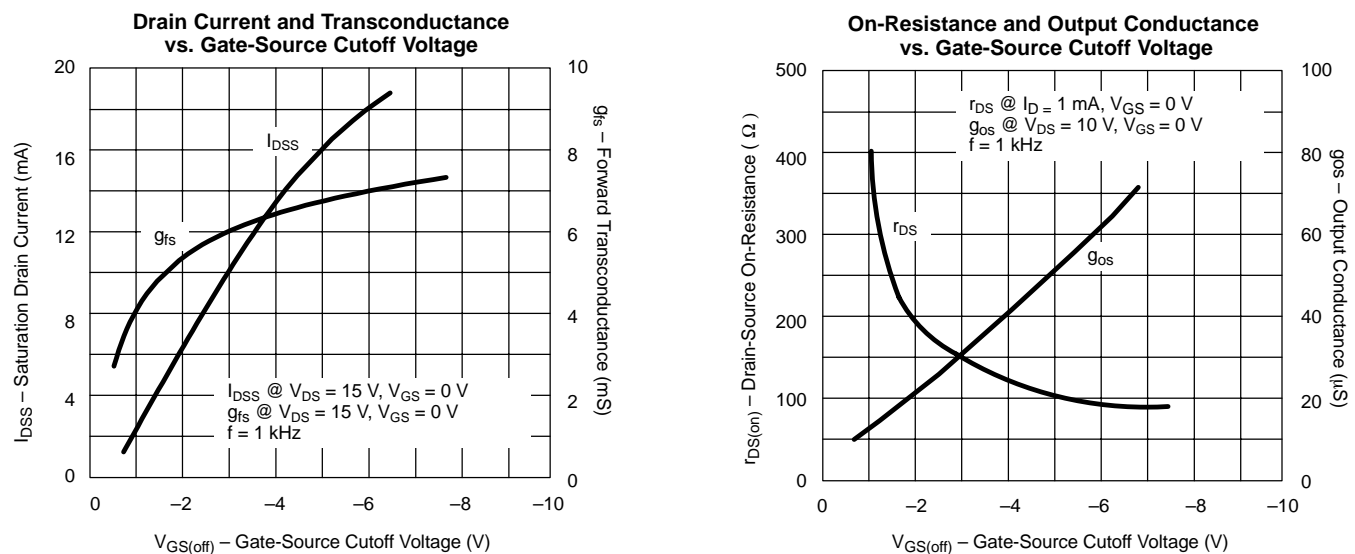
SPECIFICATIONS (T _A = 25 °C UNLESS OTHERWISE NOTED)							
Parameter	Symbol	Test Conditions	Limits			Unit	
			Min	Typ ^a	Max		
Static							
Gate-Source Breakdown Voltage	V _{(BR)GSS}	I _G = -1 μA, V _{DS} = 0 V	-25	-35		V	
Gate-Source Cutoff Voltage	V _{GS(off)}	V _{DS} = 15 V, I _D = 2 nA		-3	-8		
Saturation Drain Current ^b	I _{DSS}	V _{DS} = 15 V, V _{GS} = 0 V	2	10	20	mA	
Gate Reverse Current	I _{GSS}	V _{GS} = -15 V, V _{DS} = 0 V		-0.002	-2	nA	
		T _A = 100 °C		-0.002	-2	μA	
Gate Operating Current ^c	I _G	V _{DG} = 10 V, I _D = 1 mA		-20		pA	
Drain Cutoff Current	I _{D(off)}	V _{DS} = 10 V, V _{GS} = -8 V		2			
Drain-Source On-Resistance	r _{DS(on)}	V _{GS} = 0 V, I _D = 1 mA		150		Ω	
Gate-Source Voltage	V _{GS}	V _{DS} = 15 V, I _D = 200 μA	-0.5	-2.5	-7.5	V	
Gate-Source Forward Voltage	V _{GS(F)}	I _G = 1 mA, V _{DS} = 0 V		0.7			
Dynamic							
Common-Source Forward Transconductance ^c	g _{fs}	V _{DS} = 15 V V _{GS} = 0 V	f = 1 kHz	2	5.5	6.5	mS
			f = 100 MHz	1.6	5.5		
Common-Source Output Conductance ^c	g _{os}		f = 1 kHz		25	50	μS
Common-Source Input Capacitance	C _{iss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		2.2	8	pF	
Common-Source Reverse Transfer Capacitance	C _{rss}			0.7	4		
Equivalent Input Noise Voltage ^c	\bar{e}_n	V _{DS} = 10 V, V _{GS} = 0 V, f = 100 Hz		6		nV/ √Hz	

Notes

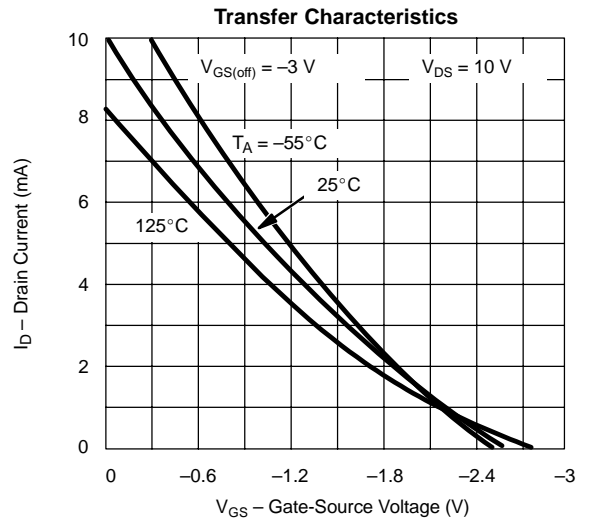
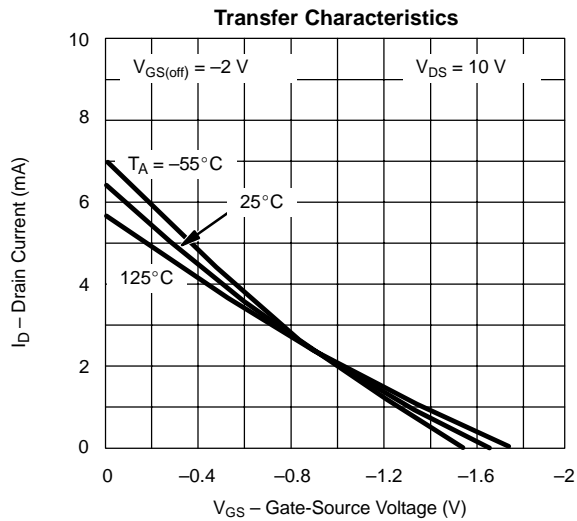
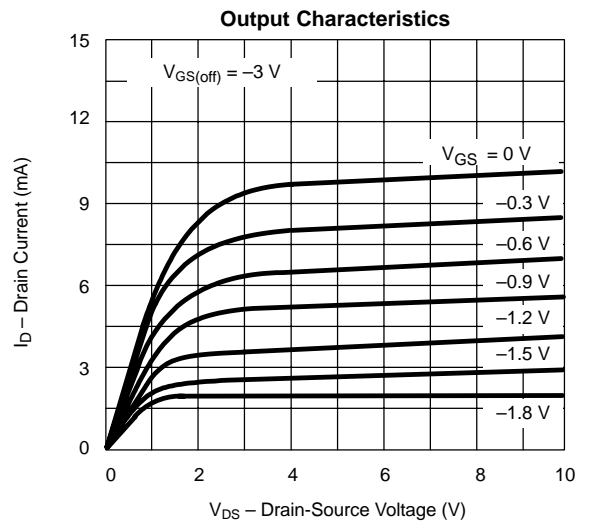
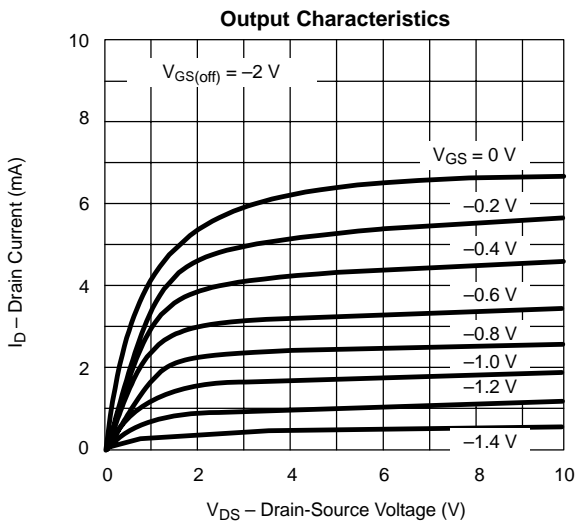
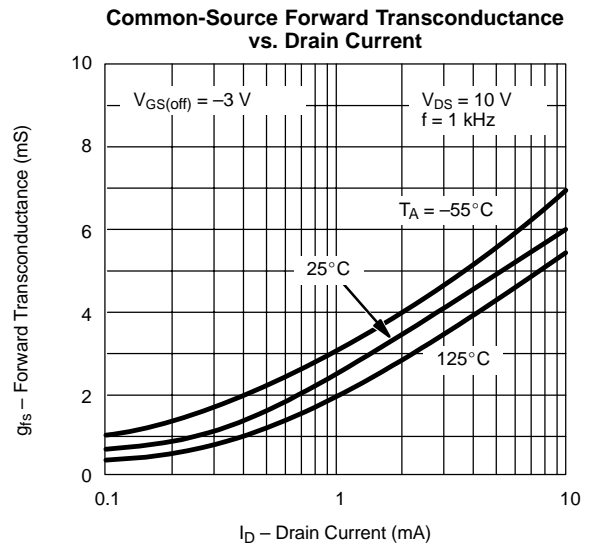
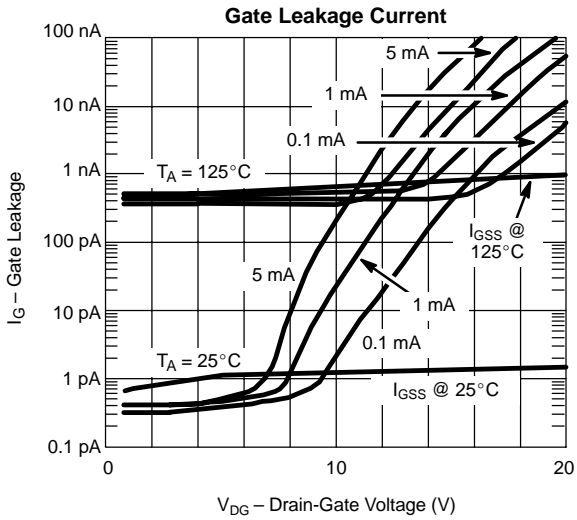
- a. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- b. Pulse test: PW ≤ 300 μs, duty cycle ≤ 2%.
- c. This parameter not registered with JEDEC.

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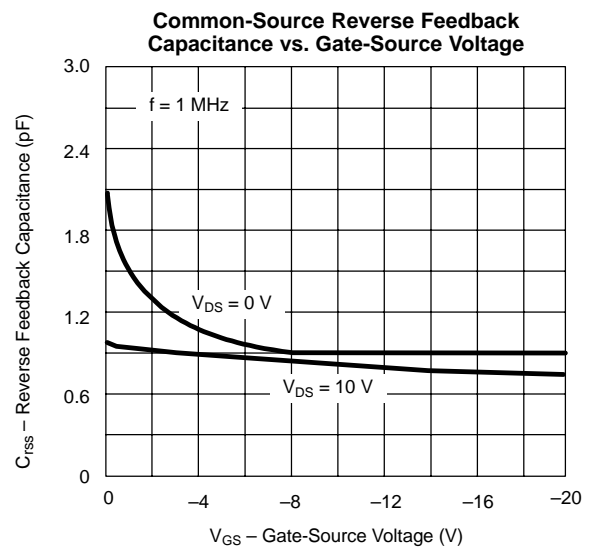
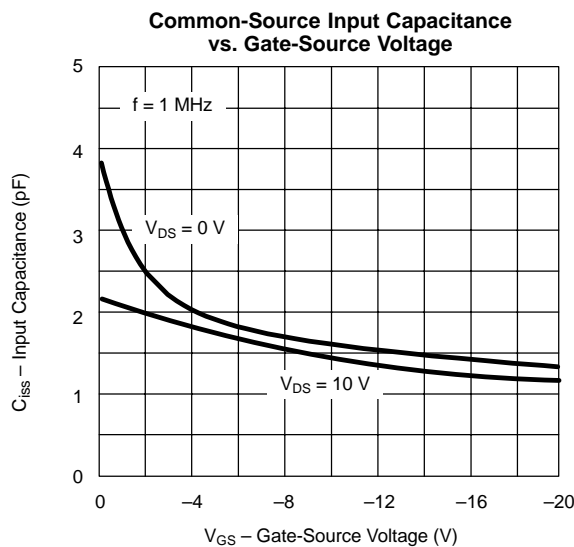
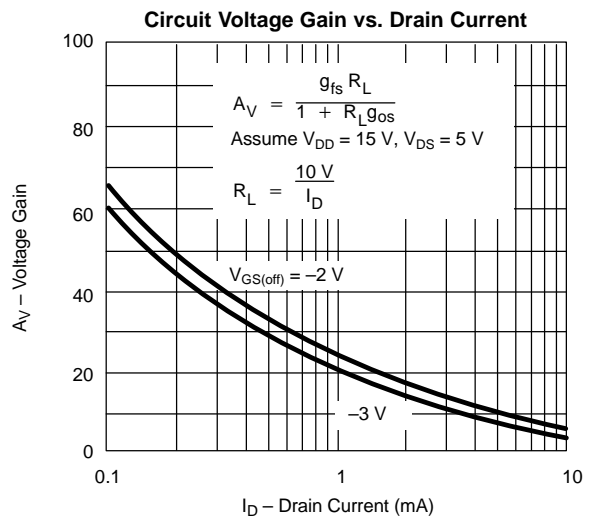
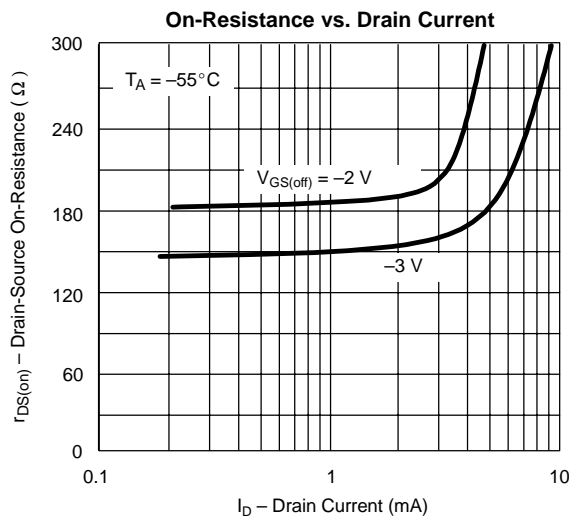
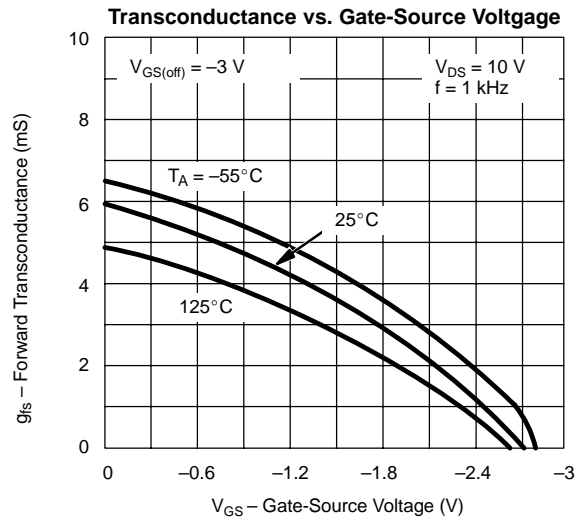
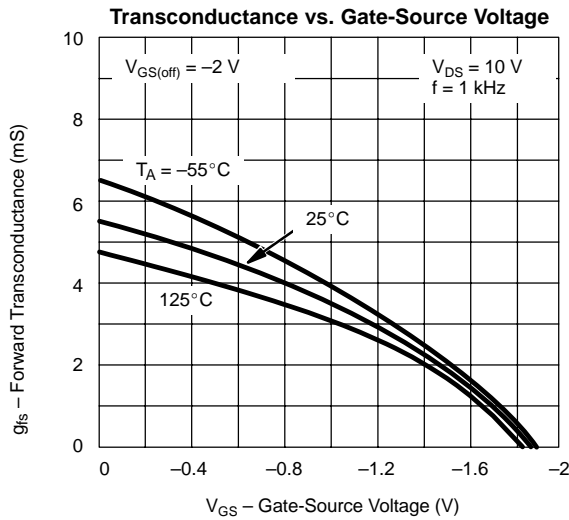
TYPICAL CHARACTERISTICS (T_A = 25 °C UNLESS OTHERWISE NOTED)



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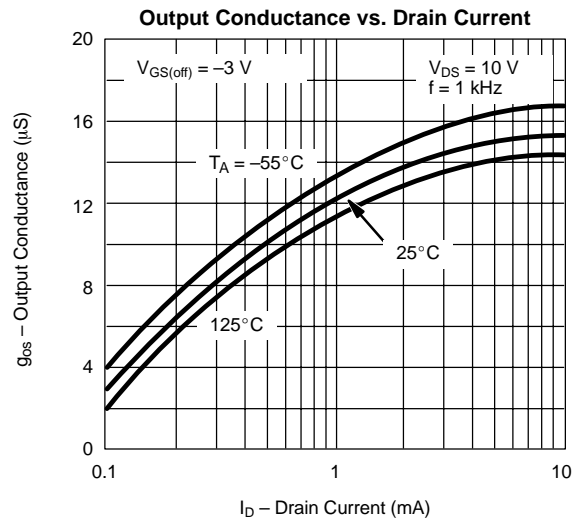
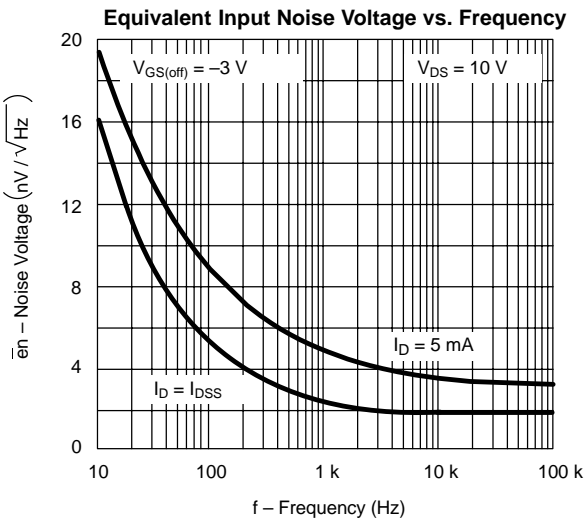
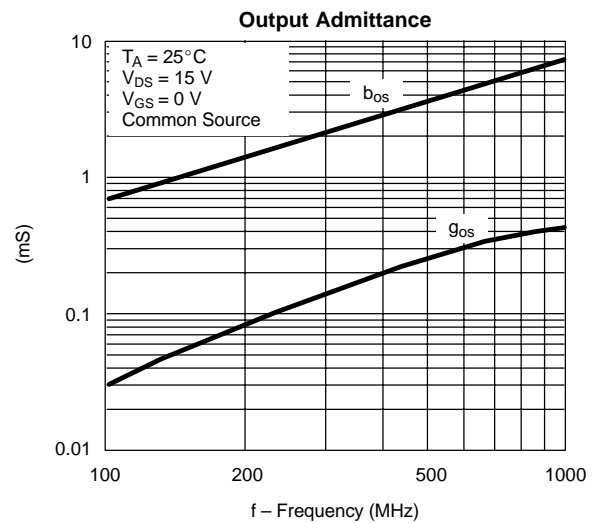
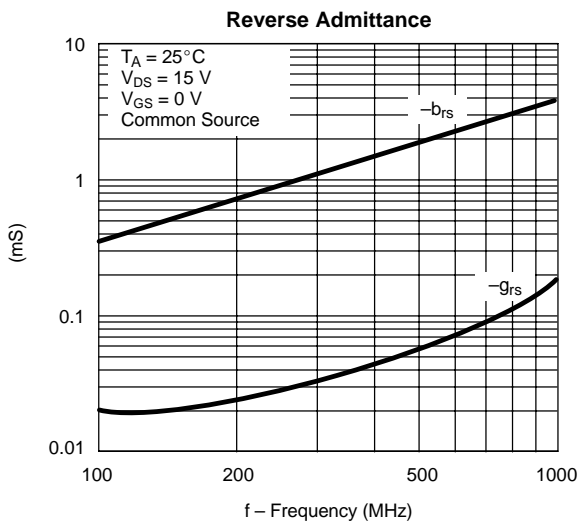
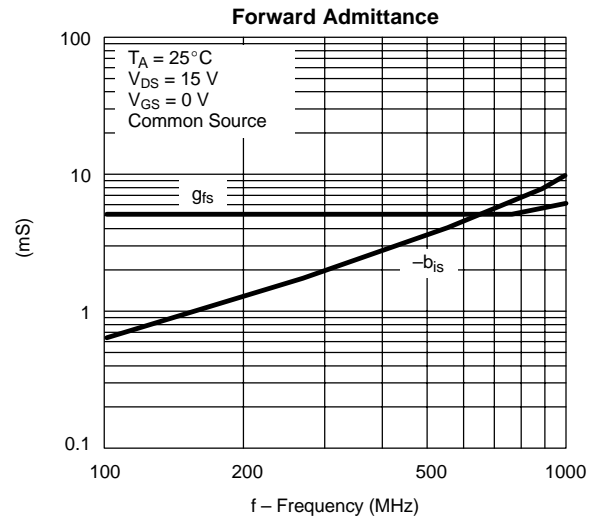
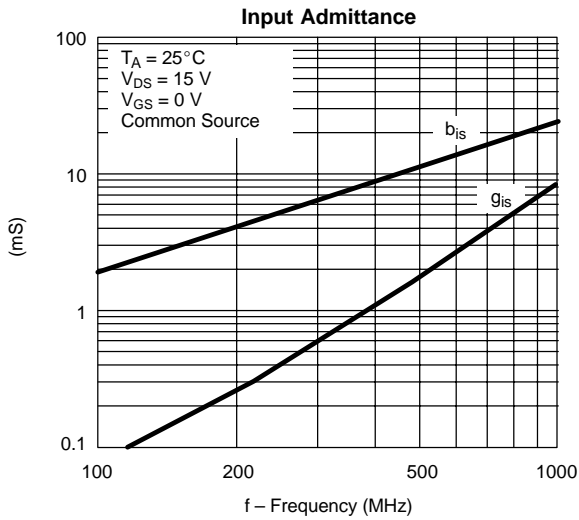


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